

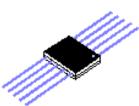
5770A

Isolated Diode Array with HiRel MQ, MX, MV, and SP Screening Options

DESCRIPTION

These low capacitance diode arrays with common anode are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 10-PIN package for use as steering diodes protecting up to eight I/O ports from ESD, EFT, or surge by directing them to ground (see figure 1). This circuit application is further complimented by the 1N5768 (separate data sheet) that has a common cathode. An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as high-density packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting.

APPEARANCE



10-PIN Ceramic Flat Pack www.*Microsemi*.cov

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

	FEATURES)	APPLICATIONS / BENEFITS
)))	Hermetic Ceramic Package Isolated Diodes To Eliminate Cross-Talk Voltages High Breakdown Voltage $V_{BR} > 60$ V at 10 μ A Low Leakage I _R < 100nA at 40 V Low Capacitance C < 8.0 pF Options for screening in accordance with MIL-PRF- 19500/474 for JAN, JANTX, JANTXV, and JANS are available by adding MQ, MX, MV, or SP prefixes respectively to part numbers. For example, designate		 High Frequency Data Lines RS-232 & RS-422 Interface Networks Ethernet: 10 Base T Computer I/O Ports LAN Switching Core Drivers IEC 61000-4 Compatible (see circuit in figure 1) 61000-4-2 ESD : Air 15kV, contact 8kW 61000-4-4 (EFT) : 40A – 5/50 ns 61000-4-5 (surge): 12A 8/20 μs
	MX5770A for a JANTX screen.		
	MAXIMUM RATINGS	יו	MECHANICAL AND PACKAGING
•	V _{BR} Reverse Breakdown Voltage 60 V min (Notes 1 & 2)		10-PIN Ceramic Flat Pack
•	$I_{\rm O}$ Continuous Forward Current 300 mA (Notes 1 & 3)		 TO-PIN Ceramic Flat Pack Weight 0.25 grams (approximate)
•	I _{FSM} Forward Surge Current (tp=1/120 s) 500 mA (Note 1)		 Marking: Logo, part number, date code and dot
•	400 mW Power Dissipation per Junction @ 25°C		identifying pin #1
•	500 mW Power Dissipation per Package @ 25°C (Note 4)		 Carrier Tubes; 19 pcs (standard)
•	Operating Junction Temperature range –65 to +150°C		
•	Storage Temperature range of –65 to +150°C	ļ	
	NOTE 1: Each Diode		

PART NUMBER	MAXIMUM FORWARD VOLTAGE V _{F1} I _F = 100 mA (Note 1)	MAXIMUM REVERSE CURRENT I_{R1} $V_{R} = 40 V$	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	MAXIMUM FORWARD RECOVERY TIME t _{fr} I _F = 500 mA	$\begin{tabular}{l} MAXIMUM \\ REVERSE \\ RECOVERY TIME \\ trr \\ I_F = I_R = 200 \mbox{ mA} \\ i_{rr} = 20 \mbox{ mA} \\ R_L = 100 \mbox{ ohms} \end{tabular}$
	Vdc	μAdc	pF	ns	ns
5770A	1	0.1	8.0	40	20

NOTE 1: Pulsed: $P_W = 300 \ \mu s \ +/-50 \ \mu s$, duty cycle $\leq 2\%$, 90 μs after leading edge.

NOTE 2: Pulsed: P_W = 100 ms max; duty cycle <20%

NOTE 3: Derate at 2.4 mA/°C above +25°C **NOTE 4:** Derate at 4.0 mW/°C above +25°C



5770A

Isolated Diode Array with HiRel MQ, MX, MV, and SP Screening Options

		SYMBOLS & DEFINITIONS					
	Symbol	DEFINITION					
_	V_{BR}	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.					
_	V _F	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.					
	I _R	Maximum Reverse Current: The maximum reverse current that will flow at the specified voltage and temperature.					
	I _{FSM}	Forward Surge Current: The peak forward surge current at a specified pulse width					
	C _t	Capacitance: The capacitance of the diode as defined @ 0 volts at a frequency of 1 MHz and stated in picofarads.					
	$2 \bigcirc 4$ $3 \bigcirc 4$ $4 \bigcirc 4$ $5 \bigcirc 4$ $6 \bigcirc 4$ $7 \bigcirc 4$ $8 \bigcirc 4$ $9 \bigcirc 4$ $01: N$	CHEMATIC 230 100 1000 1000 1000 1000 1000					
	Steering D	o (or -V _{CC}) iode Application					
	FIG	URE 1					

www.Microsemi.com

Page 2